

Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

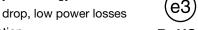
Ultra Low $V_F = 0.33 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS					
$I_{F(AV)}$	2 x 15 A				
V_{RRM}	45 V				
I _{FSM}	160 A				
V_F at $I_F = 15$ A ($T_A = 125$ °C)	0.46 V				
T_J max.	150 °C				
Package	TO-220AB				
Diode variations	Common cathode				

FEATURES

- Power pack
- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses



• High efficiency operation

RoHS COMPLIANT

Solder dip 275 °C max. 10 s, per JESD 22-B106

• Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VE3045C-E3	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	30	А	
	per diode		15		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	160	А	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5.0 A	T _A = 25 °C	- V _F ⁽¹⁾	0.44	-	V	
	I _F = 7.5 A			0.47	-		
	I _F = 15 A			0.54	0.62		
	I _F = 5.0 A	T _A = 125 °C		0.33	-		
	I _F = 7.5 A			0.37	-		
	I _F = 15 A			0.46	0.55		
Reverse current per diode	V 45.V	T _A = 25 °C	I _R ⁽²⁾	-	800	μΑ	
	$V_R = 45 \text{ V}$	T _A = 125 °C		9	35	mA	

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VE3045C-E3	UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	3.0	°C/W	
	per device		1.6		
	per device	R ₀ JA (1)(2)	55		

Notes

⁽²⁾ Free air, without heatsink

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	VE3045C-E3/45	1.93	45	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

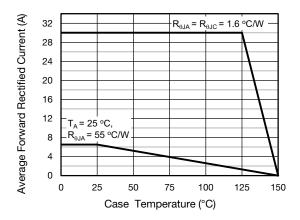


Fig. 1 - Maximum Forward Current Derating Curve

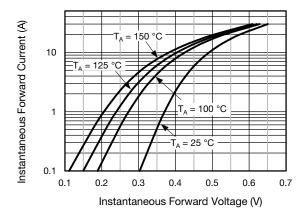


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

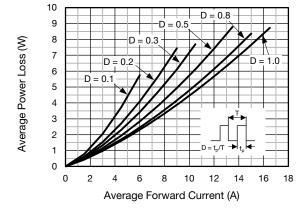


Fig. 2 - Forward Power Loss Characteristics Per Diode

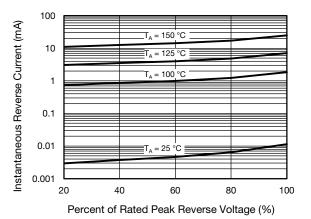
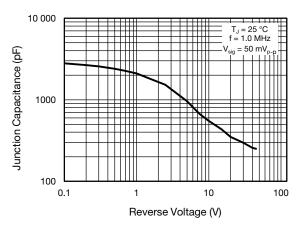


Fig. 4 - Typical Reverse Characteristics Per Diode

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $\Delta P_D/\Delta T_J < 1$ R_{8,JA}



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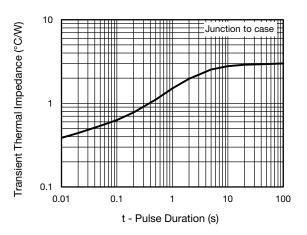
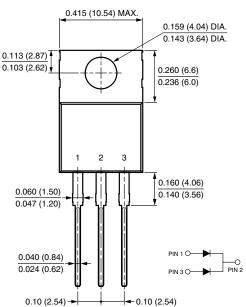
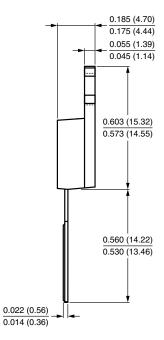


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB







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